



Docket No.: 074968-0011

PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Tetsuzo UEDA, et al.

RESPONSE UNDER 37 CFR 1.116  
EXPEDITED PROCEDURE

Application No.: 10/812,416

Customer No.: 53080

Filed: March 30, 2004

Confirmation No.: 1264

Group Art Unit: 2811

Examiner: Crane, Sara W.

Title: A 4H-POLYTYPE GALLIUM NITRIDE-BASED SEMICONDUCTOR DEVICE ON  
A 4H-POLYTYPE SUBSTRATE

**AMENDMENT UNDER 37 CFR 1.116**

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In response to the Final Office Action dated October 20, 2006, having a three-month shortened statutory period for response set to expire January 20, 2007, a two-month extension of time up to and including March 20, 2007 being filed herewith, please amend the above identified application as follows: